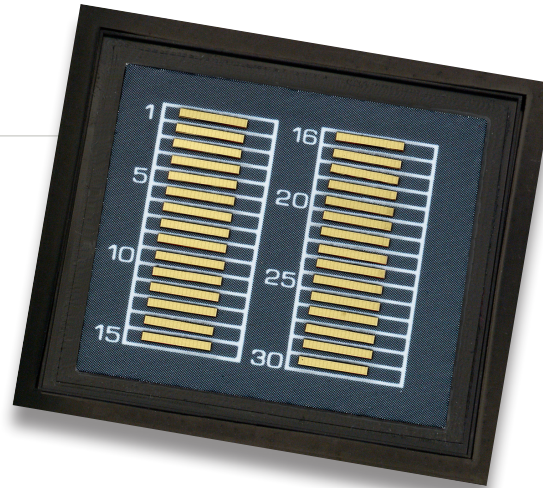


PART NUMBER: UMB200C020
LASER DIODE BAR

FEATURES AND BENEFITS



- Excellent Solderability

- Available With Any Silver or Golden Bullet® Configuration

- Lot Tested

- Available Wavelengths
(790-980nm)

OPTICAL CHARACTERISTICS

Parameter	Conditions	Min	Typ	Units
CW Power Output	26A at 25°C Heat Sink	20	—	W
Operating Current	20W at 25°C Heat Sink	—	26	A
Threshold Current	25°C Heat Sink	—	9	A
Slope Efficiency	25°C Heat Sink	—	1.15	W/A
Efficiency	20W at 25°C Heat Sink	—	45	%
Number of Emitters	—	—	46	
Emitter Size	—	—	80x1	µm
Emitter Pitch	—	—	200	µm
Center Wavelength	20W at 25°C Heat Sink	—	808	nm
Wavelength Tolerance	20W at 25°C Heat Sink	—	+/-3	nm
Spectral Width	20W at 25°C Heat Sink	—	1.8	nm
Wavelength Shift	—	—	0.25	nm/°C
Beam Divergence FWHM	—	—	40x10	°x°
Polarization	—	—	TE	

ELECTRICAL CHARACTERISTICS

Parameter	Conditions	Min	Typ	Units
Series Resistance	25°C Heat Sink	—	0.004	ohms
Operating Voltage	25°C Heat Sink, 40W	—	1.7	V

MECHANICAL CHARACTERISTICS

Parameter	Typical
Bar Width	9.6 mm
Bar Thickness	135 µm
Bar Cavity Length	1000 µm

NOTES

(1) These specifications apply for operation at 808nm. Other wavelengths available upon request.

(2) A dry nitrogen environment should be provided by the user when storing and operating at temperatures below ambient dew point.



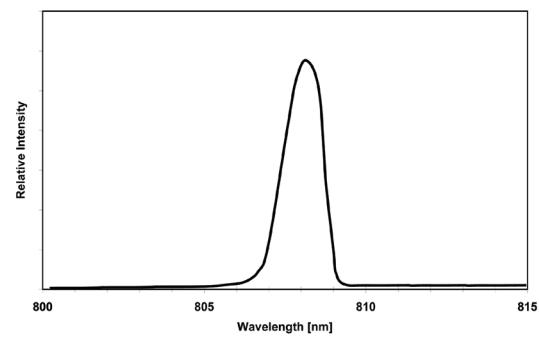
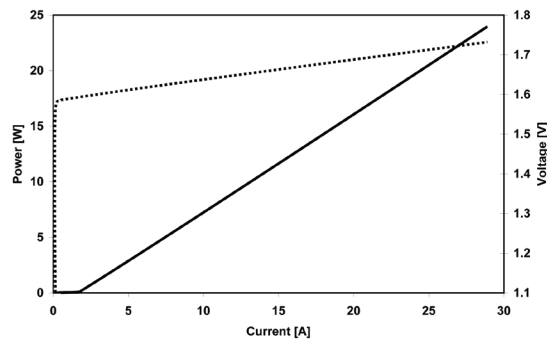
> ABSOLUTE MAXIMUM RATINGS

Parameter	Conditions
Reverse Current	0 A
Reverse Voltage	0 V
Operating Temperature Range	-40°C to 70°C
Storage Temperature Range	-40°C to 85°C

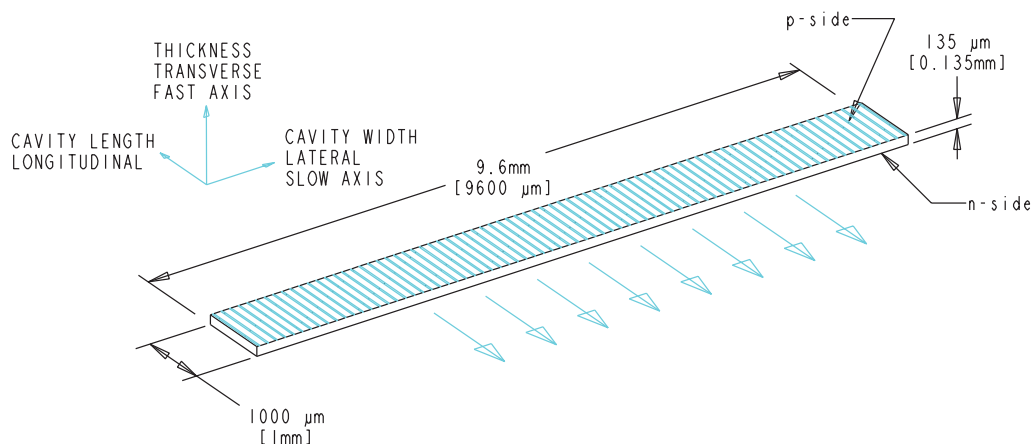
> SOLDERING CHARACTERISTICS

Parameter	Conditions
Metalization	1000 Å Au over Pt barrier

> OPTICAL CHARACTERISTICS (TYPICAL)



> MECHANICAL CHARACTERISTICS



Copyright © 2003 Northrop Grumman Cutting Edge Optronics All Rights Reserved. Northrop Grumman Cutting Edge Optronics reserves the right to change product design and specifications at any time without notice. No license is granted by implication or otherwise under any patents or patent rights of Northrop Grumman Cutting Edge Optronics or others. No responsibility is assumed for the use of these products, nor for any infringement on the rights of others resulting from the use of these products. Information contained herein is believed to be reliable and accurate. Laser diode product components are intended for use in a user-devised end system. However, these products are capable of emitting Class IV radiation. Extreme care must be exercised during their operation. Only persons familiar with the appropriate safety precautions should operate a laser product. Directly viewing the laser beam or exposure to specular reflections must be avoided. Serious injury may result if any part of the body is exposed to the beam. The eye is extremely sensitive to the infrared radiation and therefore, proper eyewear must be worn at all times. Use of optical instruments with these products may increase eye hazard. Always wear proper eye protection when operating. This Product is covered by one or more of the following Patents: 5,898,211 | 5,985,684 | 5,913,108 | 6,310,900 | Other US and Foreign Patents Pending. Notes (1) These specifications apply for operation at 808nm. Other wavelengths available upon request. (2) A dry nitrogen environment should be provided by the user when storing and operating at temperatures below ambient dew point.

⚠ DANGER ⚠

INVISIBLE LASER RADIATION
AVOID EYE OR SKIN EXPOSURE TO DIRECT OR SCATTERED RADIATION

* Diode laser
SW & up, 790-1560nm
CLASS IV

⚠ WARNING ⚠

ELECTROSTATIC DISCHARGE SENSITIVE DEVICE
REQUIRING SPECIAL HANDLING

Rev. C 02/08 ISO 9001:2000 Registered